



## Power Schottky rectifier

## Main product characteristics

I <sub>F(AV)</sub>	7.5 A
V <sub>RRM</sub>	45 V
T <sub>j</sub> (max)	150° C
V <sub>F</sub> (max)	0.57 V

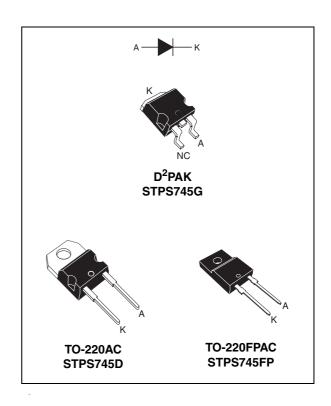
### **Features and Benefits**

- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Insulated package: TO-220FPAC
   Insulating voltage = 2000 V DC
   Capacitance = 12 pF
- Avalanche capability specified

### **Description**

Single Schottky rectifier suited for Switch Mode Power Supply and high frequency DC to DC converters.

Packaged either in TO-220AC, TO-220FPAC or D<sup>2</sup>PAK, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.



**Characteristics STPS745** 

## **Characteristics**

Table 1. **Absolute Ratings (limiting values)** 

Symbo I	Parameter				Unit
$V_{RRM}$	Repetitive peak reverse voltage			45	V
I <sub>F(RMS)</sub>	RMS forward voltage			20	Α
I <sub>F(AV)</sub>	Average forward current $\delta = 0.5$	TO-220AC / D <sup>2</sup> PAK	T <sub>c</sub> = 160° C	7.5	А
. (/ (* /	0 = 0.5	TO-220FPAC	T <sub>c</sub> = 145° C		
I <sub>FSM</sub>	Surge non repetitive forward current	ive forward current $t_p = 10 \text{ ms Sinusoidal}$			Α
I <sub>RRM</sub>	Repetitive peak reverse current	epetitive peak reverse current $t_p = 2 \mu s square F = 1 kHz$			Α
I <sub>RSM</sub>	Non repetitive peak reverse current $t_p = 100 \mu s$ square			2	Α
P <sub>ARM</sub>	Repetitive peak avalanche power $t_p = 1 \mu s T_j = 25^{\circ} C$			2700	W
T <sub>stg</sub>	Storage temperature range			-65 to + 175	°C
Tj	Maximum operating junction temperature (1)			175	°C
dV/dt	Critical rate of rise of reverse voltage			10000	V/µs

<sup>1.</sup>  $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$  thermal runaway condition for a diode on its own heatsink

Table 2. Thermal resistances

Symbol	Parameter V			Unit
R <sub>th (j-c)</sub> Junction to case	lunction to case	TO-220AC / D <sup>2</sup> PAK	3.0	°C/W
	Juniciion to case	TO-220FPAC	5.5	

Table 3. Static electrical characteristics (per diode)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I <sub>B</sub> <sup>(1)</sup>	L (1) Payaraa laakaga ayurrant		$V_R = V_{RRM}$			100	μΑ
I <sub>R</sub> <sup>(1)</sup> Reverse leakage current	T <sub>j</sub> = 125° C			5	15	mA	
		T <sub>j</sub> = 125° C	I <sub>F</sub> = 7.5 A		0.5	0.57	
V <sub>F</sub> <sup>(1)</sup> Forward voltage drop	Forward voltage drop	T <sub>j</sub> = 25° C	I <sub>F</sub> = 15 A			0.84	V
		T <sub>j</sub> = 125° C	I <sub>F</sub> = 15 A		0.65	0.72	

<sup>1.</sup> Pulse test:  $tp = 380 \mu s$ ,  $\delta < 2\%$ 

To evaluate the conduction losses use the following equation: P = 0.42 x  $I_{F(AV)}$  + 0.020  $I_{F}^{2}_{(RMS)}$ 

$$P = 0.42 \text{ x } I_{F(AV)} + 0.020 I_{F^2(RMS)}$$

STPS745 Characteristics

Figure 1. Average forward power dissipation Figure 2. Average forward current versus versus average forward current ambient temperature ( $\delta$  = 0.5)

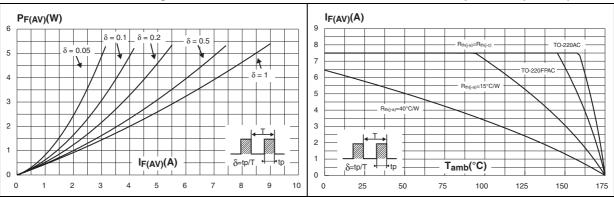


Figure 3. Normalized avalanche power derating versus pulse duration

Figure 4. Normalized avalanche power derating versus junction temperature

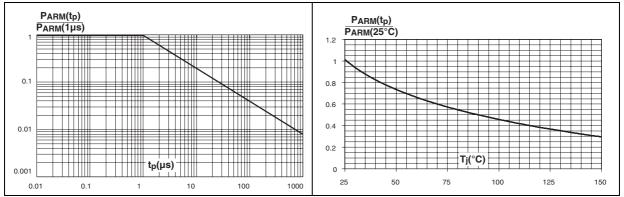
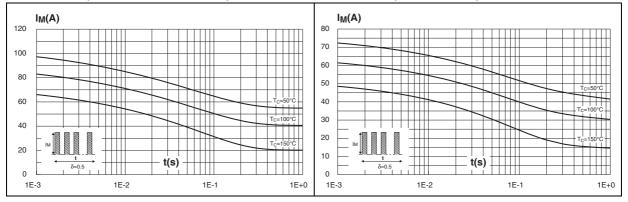


Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values)
(TO-220AC and D<sup>2</sup>PAK)

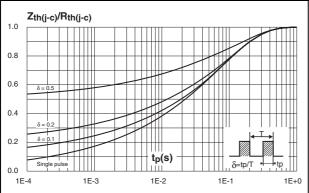
Figure 6. Non repetitive surge peak forwardcurrent versus overload duration (maximum values) (TO-220FPAC)



Characteristics STPS745

Figure 7. Relative variation of thermal transient impedance junction to case versus pulse duration (TO-220AC and D<sup>2</sup>PAK)

Figure 8. Relative variation of thermal transient impedance junction to case versus pulse duration (TO-220FPAC)



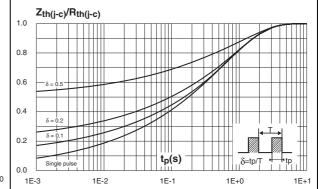
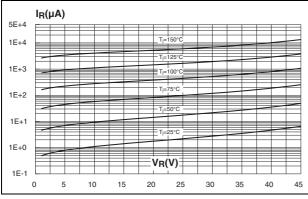


Figure 9. Reverse leakage current versus reverse voltage applied (typical values)

Figure 10. Junction capacitance versus reverse voltage applied (typical values)



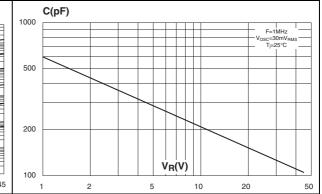
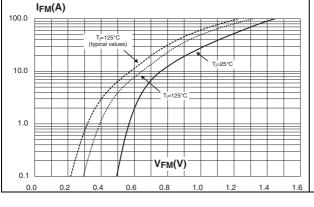
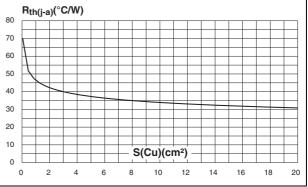


Figure 11. Forward voltage drop versus forward current (maximum values)

Figure 12. Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board, copper thickness: 35 µm)





**STPS745 Package information** 

#### **Package information** 2

Epoxy meets UL94, V0

Cooling method: by conduction (C) Recommended torque value: 0.55 Nm Maximum torque value: 0.70 Nm

D<sup>2</sup>PAK dimensions Table 4.

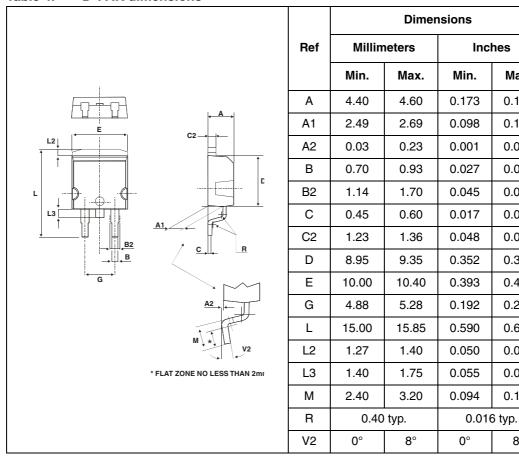
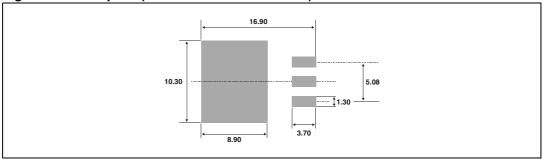


Figure 13. Footprint (dimensions in millimeters)



Max.

0.181

0.106

0.009

0.037

0.067

0.024

0.054

0.368

0.409

0.208

0.624

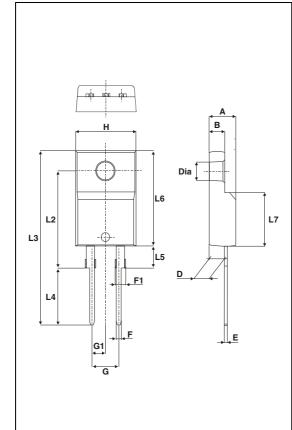
0.055

0.069

0.126

Package information STPS745

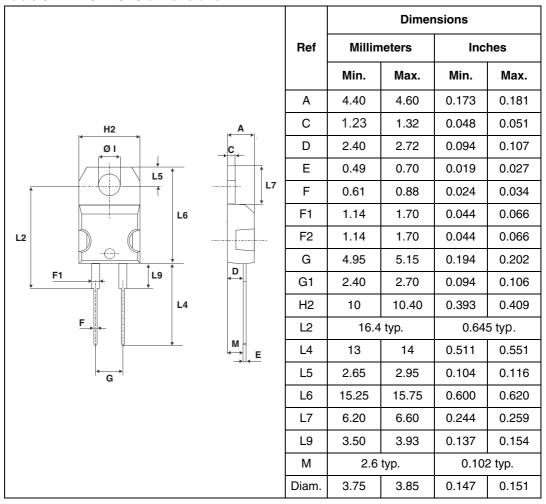
Table 5. TO-220FPAC dimensions



	Dimensions				
Ref	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
Α	4.4	4.6	0.173	0.181	
В	2.5	2.7	0.098	0.106	
D	2.5	2.75	0.098	0.108	
Е	0.45	0.70	0.018	0.027	
F	0.75	1	0.030	0.039	
F1	1.15	1.70	0.045	0.067	
G	4.95	5.20	0.195	0.205	
G1	2.4	2.7	0.094	0.106	
Н	10	10.4	0.393	0.409	
L2	16 <sup>-</sup>	Тур.	0.63 Typ.		
L3	28.6	30.6	0.126	1.205	
L4	9.8	10.6	0.386	0.417	
L5	2.9	3.6	0.114	0.142	
L6	15.9	16.4	0.626	0.646	
L7	9.00	9.30	0.354	0.366	
Dia.	3.00	3.20	0.118	0.126	

STPS745 Package information

Table 6. TO-220AC dimensions



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Ordering information STPS745

# 3 Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS745D	STPS745D	TO-220AC	1.86 g	50	Tube
STPS745G	STPS745G	D <sub>2</sub> PAK	1.48 g	50	Tube
STPS745G-TR	STPS745G	D <sub>2</sub> PAK	1.48 g	1000	Tape & reel
STPS745FP	STPS745FP	TO-220FPAC	1.9 g	50	Tube

# 4 Revision history

Date	Revision	Description of Changes
Jul-2003	6G	Last release.
22-Mar-2007	7	Removed ISOWATT package.

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